BLP05H6150XR; BLP05H6150XRG

Power LDMOS transistor

Rev. 4 — 21 September 2016

AMPLEON

Product data sheet

1. Product profile

1.1 General description

A 150 W extremely rugged LDMOS power transistor for broadcast and industrial applications in the HF to 600 MHz band.

Table 1. Application information

Test signal	f	V_{DS}	P_L	G_p	η_D	ACPR
	(MHz)	(V)	(W)	(dB)	(%)	(dBc)
pulsed RF	108	50	150	27	75	-
CW	1.8 to 30	50	100	29	60	-
	135	50	150	26	73	-
	174 to 230	50	150	22	67	-
DVB-T	174 to 230	50	25	23	29	−36

1.2 Features and benefits

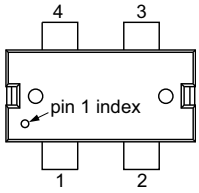
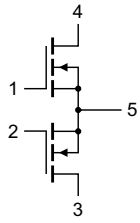
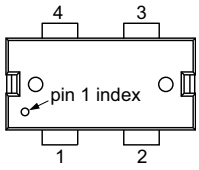
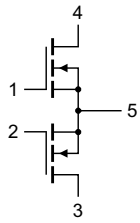
- Easy power control
- Integrated double sided ESD protection
- Excellent ruggedness
- High efficiency
- Excellent thermal stability
- Designed for broadband operation (HF to 600 MHz)
- Compliant to Directive 2002/95/EC, regarding Restriction of Hazardous Substances (RoHS)

1.3 Applications

- Industrial, scientific and medical applications
- Broadcast transmitter applications

2. Pinning information

Table 2. Pinning

Pin	Description	Simplified outline	Graphic symbol
BLP05H6150XR (SOT1223-2)			
1	gate 2		
2	gate 1		
3	drain 1		
4	drain 2		
5	source [1]		
BLP05H6150XRG (SOT1224-2)			
1	gate 2		
2	gate 1		
3	drain 1		
4	drain 2		
5	source [1]		

[1] Connected to flange.

3. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
BLP05H6150XR	HSOP4F	plastic, heatsink small outline package; 4 leads (flat)	SOT1223-2
BLP05H6150XRG	HSOP4F	plastic, heatsink small outline package; 4 leads	SOT1224-2

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DS}	drain-source voltage		-	135	V
V_{GS}	gate-source voltage		–6	+11	V
T_{stg}	storage temperature		–65	+150	°C
T_j	junction temperature	[1]	-	225	°C

[1] Continuous use at maximum temperature will affect the reliability, for details refer to the online MTF calculator.

5. Thermal characteristics

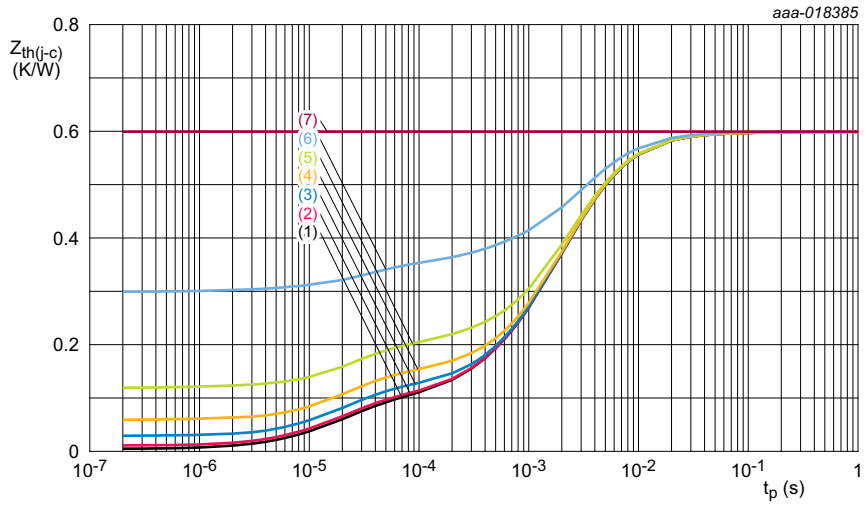
Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Typ	Unit
$R_{th(j-c)}$	thermal resistance from junction to case	T_j = 125 °C [1][2]	0.6	K/W
$Z_{th(j-c)}$	transient thermal impedance from junction to case	T_j = 150 °C; t_p = 100 μs; δ = 20 % [3]	0.21	K/W

[1] T_j is the junction temperature.

[2] $R_{th(j-c)}$ is measured under RF conditions.

[3] See Figure 1.



(1) δ = 1 %
(2) δ = 2 %
(3) δ = 5 %
(4) δ = 10 %
(5) δ = 20 %
(6) δ = 50 %
(7) δ = 100 % (DC)

Fig 1. Transient thermal impedance from junction to case as a function of pulse duration

6. Characteristics

Table 6. DC characteristics

T_j = 25 °C; per section unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$V_{(BR)DSS}$	drain-source breakdown voltage	V_{GS} = 0 V; I_D = 0.5 mA	135	-	-	V
$V_{GS(th)}$	gate-source threshold voltage	V_{DS} = 10 V; I_D = 50 mA	1.25	1.8	2.25	V
V_{GSq}	gate-source quiescent voltage	V_{DS} = 50 V; I_D = 20 mA	-	1.7	-	V

Table 6. DC characteristics *...continued*

T_j = 25 °C; per section unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
I_{DSS}	drain leakage current	V_{GS} = 0 V; V_{DS} = 50 V	-	-	1.4	μA
I_{DSX}	drain cut-off current	V_{GS} = $V_{GS(th)}$ + 3.75 V; V_{DS} = 10 V	-	7.2	-	A
I_{GSS}	gate leakage current	V_{GS} = 11 V; V_{DS} = 0 V	-	-	140	nA
$R_{DS(on)}$	drain-source on-state resistance	V_{GS} = $V_{GS(th)}$ + 3.75 V; I_D = 1.75 A	-	0.8	-	Ω

Table 7. AC characteristics

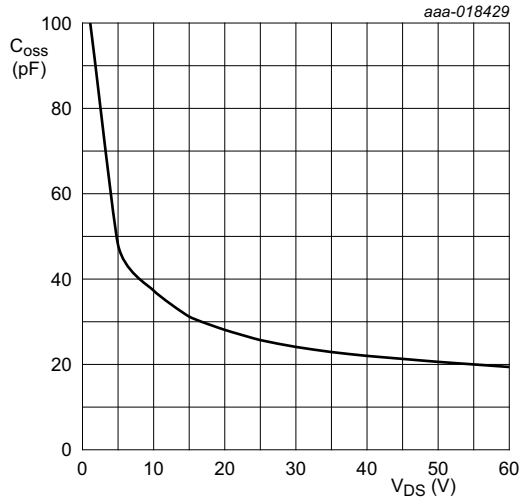
T_j = 25 °C; per section unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
C_{rs}	feedback capacitance	V_{GS} = 0 V; V_{DS} = 50 V; f = 1 MHz	-	0.5	-	pF
C_{iss}	input capacitance	V_{GS} = 0 V; V_{DS} = 50 V; f = 1 MHz	-	60	-	pF
C_{oss}	output capacitance	V_{GS} = 0 V; V_{DS} = 50 V; f = 1 MHz	-	21	-	pF

Table 8. RF characteristics

Test signal: pulsed RF; t_p = 100 μs; δ = 20 %; f = 108 MHz; RF performance at V_{DS} = 50 V; I_{Dq} = 100 mA; T_{case} = 25 °C; unless otherwise specified; in a class-AB production test circuit.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
G_p	power gain	P_L = 150 W	25.5	27	-	dB
RL_{in}	input return loss	P_L = 150 W	-	−8	-	dB
η_D	drain efficiency	P_L = 150 W	73	75	-	%



V_{GS} = 0 V; f = 1 MHz.

Fig 2. Output capacitance as a function of drain-source voltage; typical values per section

7. Test information

7.1 Ruggedness in class-AB operation

The BLP05H6150XR and BLP05H6150XRG are capable of withstanding a load mismatch corresponding to VSWR > 65 : 1 through all phases under the following conditions: V_{DS} = 50 V; I_{Dq} = 40 mA; P_L = 150 W pulsed; f = 108 MHz.

7.2 Impedance information

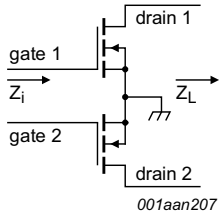


Fig 3. Definition of transistor impedance

Table 9. Typical push-pull impedance

Simulated Z_i and Z_L device impedance; impedance info at V_{DS} = 50 V and P_L = 150 W.

f	Z_i	Z_L
(MHz)	(Ω)	(Ω)
108	32 − j99	25 + j6.0

7.3 UIS avalanche energy

Table 10. Typical avalanche data per section

T_{amb} = 25 °C; typical test data; test jig without water cooling.

I_{AS}	E_{AS}
(A)	(J)
4	0.38
5	0.26
6	0.18

For information see application note *AN10273*.

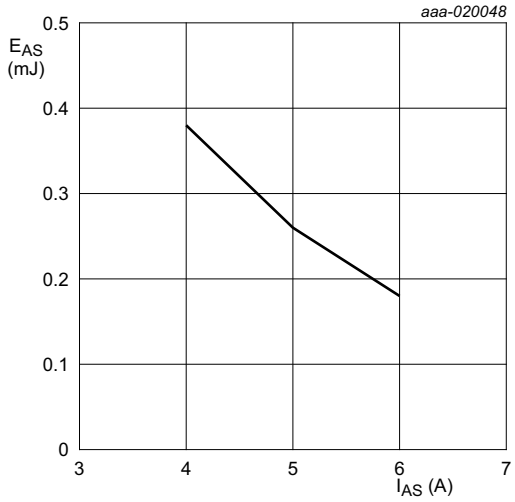
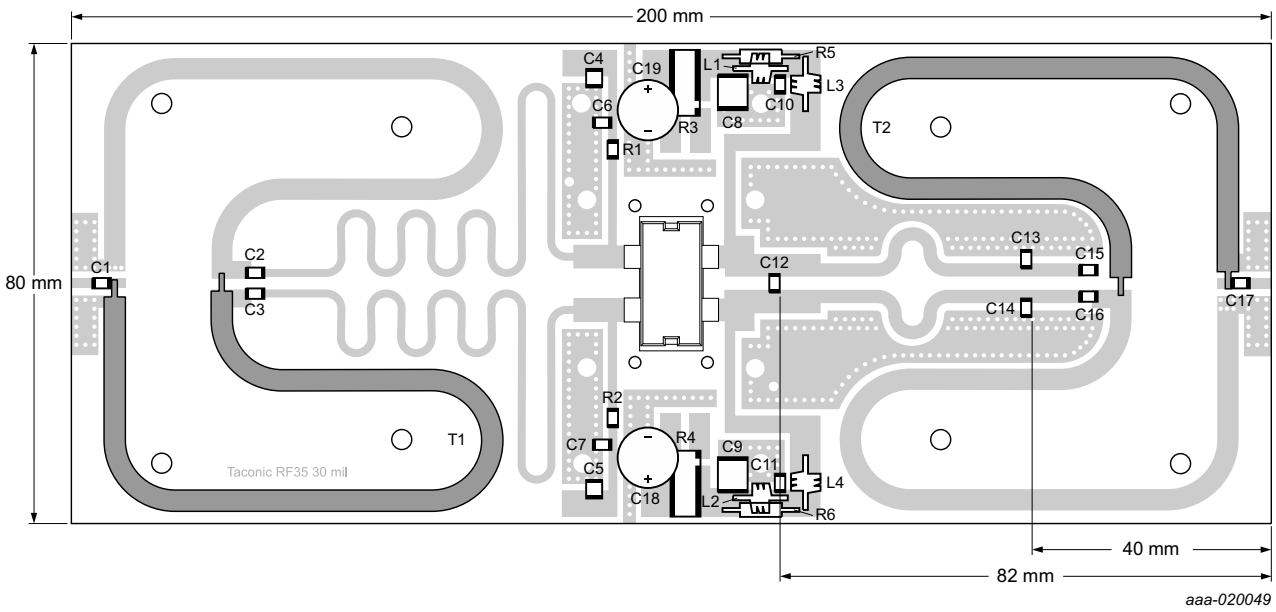


Fig 4. Non-repetitive avalanche energy as a function of single pulse avalanche current; typical values

7.4 Test circuit



Printed-Circuit Board (PCB): RF-35; ε_r = 3.5 F/m; thickness = 0.765 mm; thickness copper plating = 35 μm.

See Table 11 for a list of components.

Fig 5. Component layout for class-AB production test circuit

Table 11. List of components

For test circuit see Figure 5.

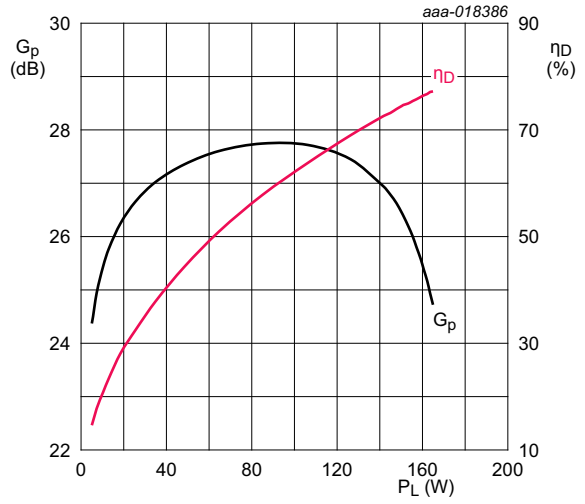
Component	Description	Value	Remarks
C1	multilayer ceramic chip capacitor	68 pF [1]	
C2, C3	multilayer ceramic chip capacitor	220 pF [1]	
C4, C5	multilayer ceramic chip capacitor	4.7 μF, 50 V	Kemet: C1210X475K5RAC-T4
C6, C7	multilayer ceramic chip capacitor	750 pF [1]	
C8, C9	multilayer ceramic chip capacitor	4.7 μF, 100 V	TDK: C5750X7R2A475KT
C10, C11	multilayer ceramic chip capacitor	750 pF [1]	
C12	multilayer ceramic chip capacitor	10 pF [1]	
C13, C14	multilayer ceramic chip capacitor	43 pF [1]	
C15, C16	multilayer ceramic chip capacitor	390 pF [1]	
C17	multilayer ceramic chip capacitor	47 pF [1]	
C18,C19	electrolytic capacitor	2200 μF, 64 V	
L1, L2	wire inductor	5 turns, D = 3 mm, 1 mm copper wire	
L3, L4	wire inductor	6 turns, D = 3 mm, 1 mm copper wire	
R1, R2	resistor	4.7 kΩ	SMD 1206
R3, R4	shunt resistor	0.01 Ω	Ohmite: FC4L110R010FER
R5, R6	metal film resistor	10 Ω, 0.6 W	
T1, T2	semi rigid coax	50 Ω, length = 160 mm	EZ Form: EZ-141-AL-TP-M17

[1] American Technical Ceramics type 100B or capacitor of same quality.

7.5 Graphical data

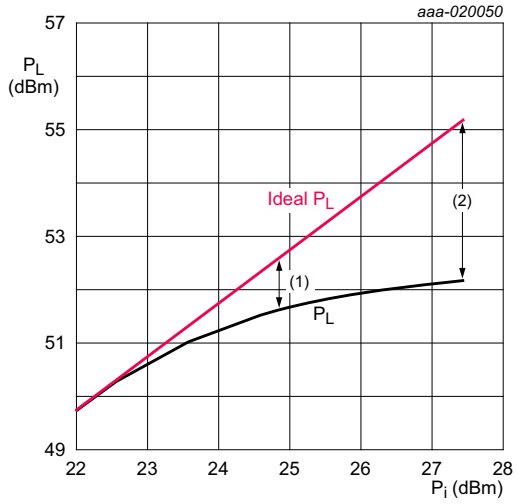
The following figures are measured in a class-AB production test circuit.

7.5.1 1-Tone CW pulsed



V_{DS} = 50 V; I_{Dq} = 40 mA; f = 108 MHz; t_p = 100 μs; δ = 20 %.

Fig 6. Power gain and drain efficiency as function of output power; typical values

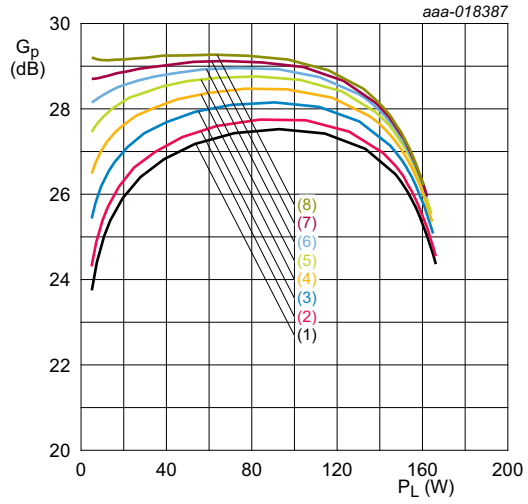


V_{DS} = 50 V; I_{Dq} = 40 mA; f = 108 MHz; t_p = 100 μs; δ = 20 %.

(1) $P_{L(1dB)}$ = 51.6 dBm (146 W)

(2) $P_{L(3dB)}$ = 52.2 dBm (165 W)

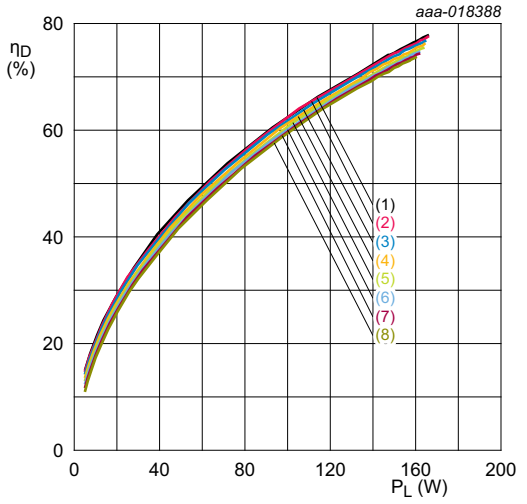
Fig 7. Output power as a function of input power; typical values



V_{DS} = 50 V; f = 108 MHz; t_p = 100 μs; δ = 20 %.

(1) I_{Dq} = 20 mA
(2) I_{Dq} = 40 mA
(3) I_{Dq} = 100 mA
(4) I_{Dq} = 200 mA
(5) I_{Dq} = 300 mA
(6) I_{Dq} = 400 mA
(7) I_{Dq} = 500 mA
(8) I_{Dq} = 600 mA

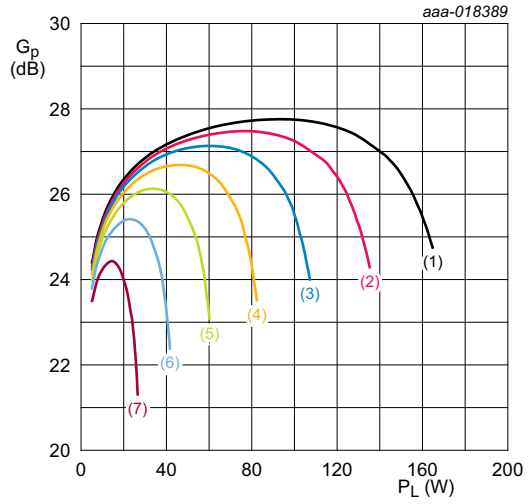
Fig 8. Power gain as a function of output power; typical values



V_{DS} = 50 V; f = 108 MHz; t_p = 100 μs; δ = 20 %.

(1) I_{Dq} = 20 mA
(2) I_{Dq} = 40 mA
(3) I_{Dq} = 100 mA
(4) I_{Dq} = 200 mA
(5) I_{Dq} = 300 mA
(6) I_{Dq} = 400 mA
(7) I_{Dq} = 500 mA
(8) I_{Dq} = 600 mA

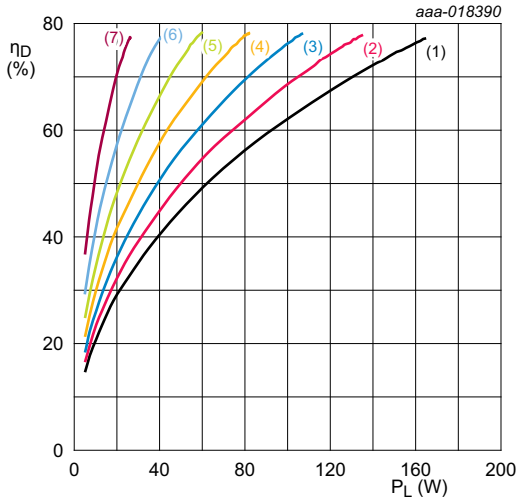
Fig 9. Drain efficiency as a function of output power; typical values



I_{Dq} = 40 mA; f = 108 MHz; t_p = 100 μs; δ = 20 %.

(1) V_{DS} = 50 V
(2) V_{DS} = 45 V
(3) V_{DS} = 40 V
(4) V_{DS} = 35 V
(5) V_{DS} = 30 V
(6) V_{DS} = 25 V
(7) V_{DS} = 20 V

Fig 10. Power gain as a function of output power; typical values



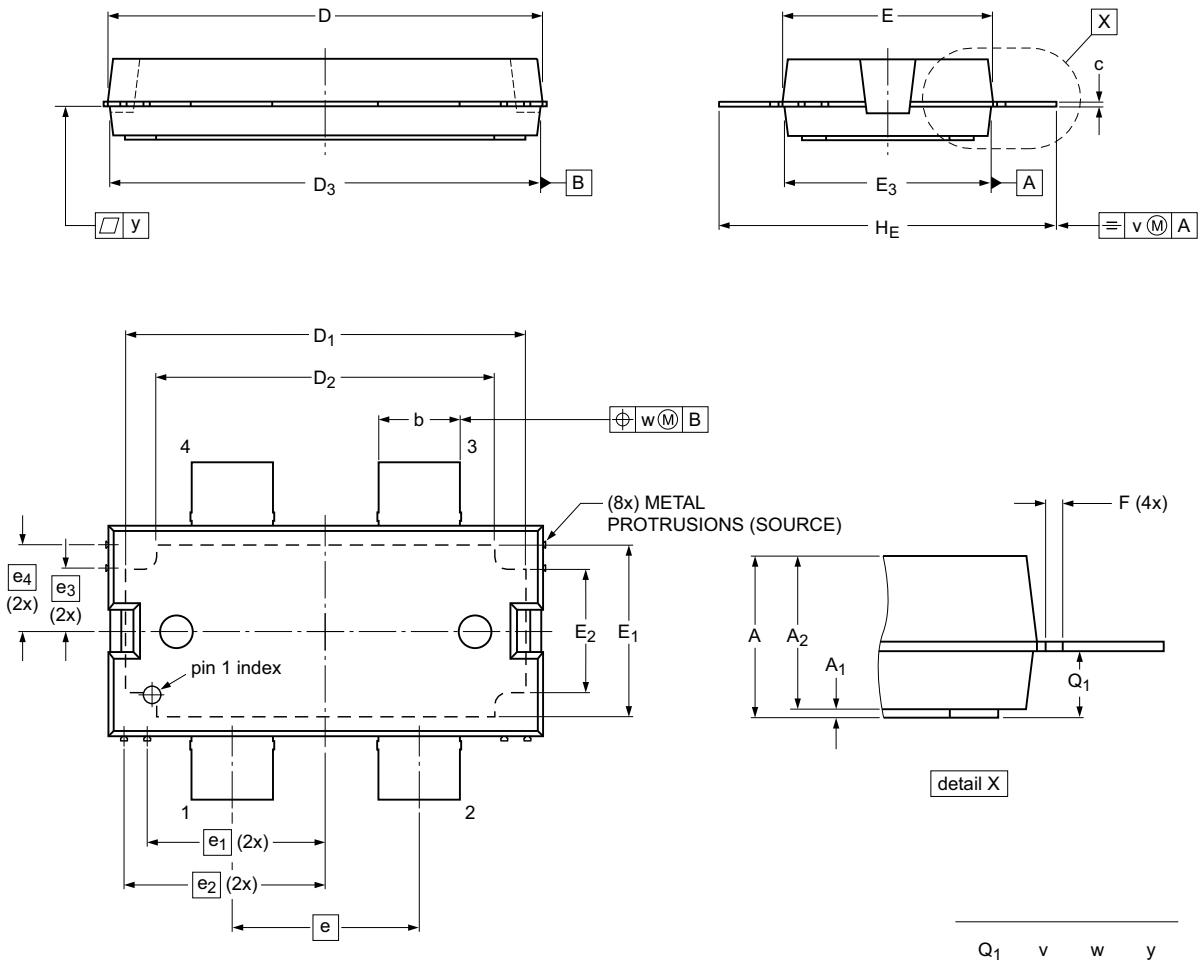
I_{Dq} = 40 mA; f = 108 MHz; t_p = 100 μs; δ = 20 %.

(1) V_{DS} = 50 V
(2) V_{DS} = 45 V
(3) V_{DS} = 40 V
(4) V_{DS} = 35 V
(5) V_{DS} = 30 V
(6) V_{DS} = 25 V
(7) V_{DS} = 20 V

Fig 11. Drain efficiency as a function of output power; typical values

8. Package outline

HSOP4F: plastic, heatsink small outline package; 4 leads(flat) **SOT1223-2**



Q_1	v	w	y
1.62			0.1
1.57	0.25	0.25	
1.52			

Dimensions (mm are the original dimensions)

Unit		A	A_1	A_2	b	c	$D^{(1)}$	D_1	D_2	D_3	$E^{(1)}$	E_1	E_2	E_3	e	e_1	e_2	e_3	e_4	F	H_E
	max	3.9	0.2	3.65	3.90	0.27	20.62	19.00	16.05	20.44	10.01	8.18	5.89	9.83							16.16
mm	nom		0.1	3.60	3.85	0.22	20.57	18.95	16.00	20.39	9.96	8.13	5.84	9.78	8.85	8.45	9.55	2.97	4.07	0.4	15.96
	min		0	3.55	3.80	0.17	20.52	18.90	15.95	20.34	9.91	8.08	5.79	9.73							15.76

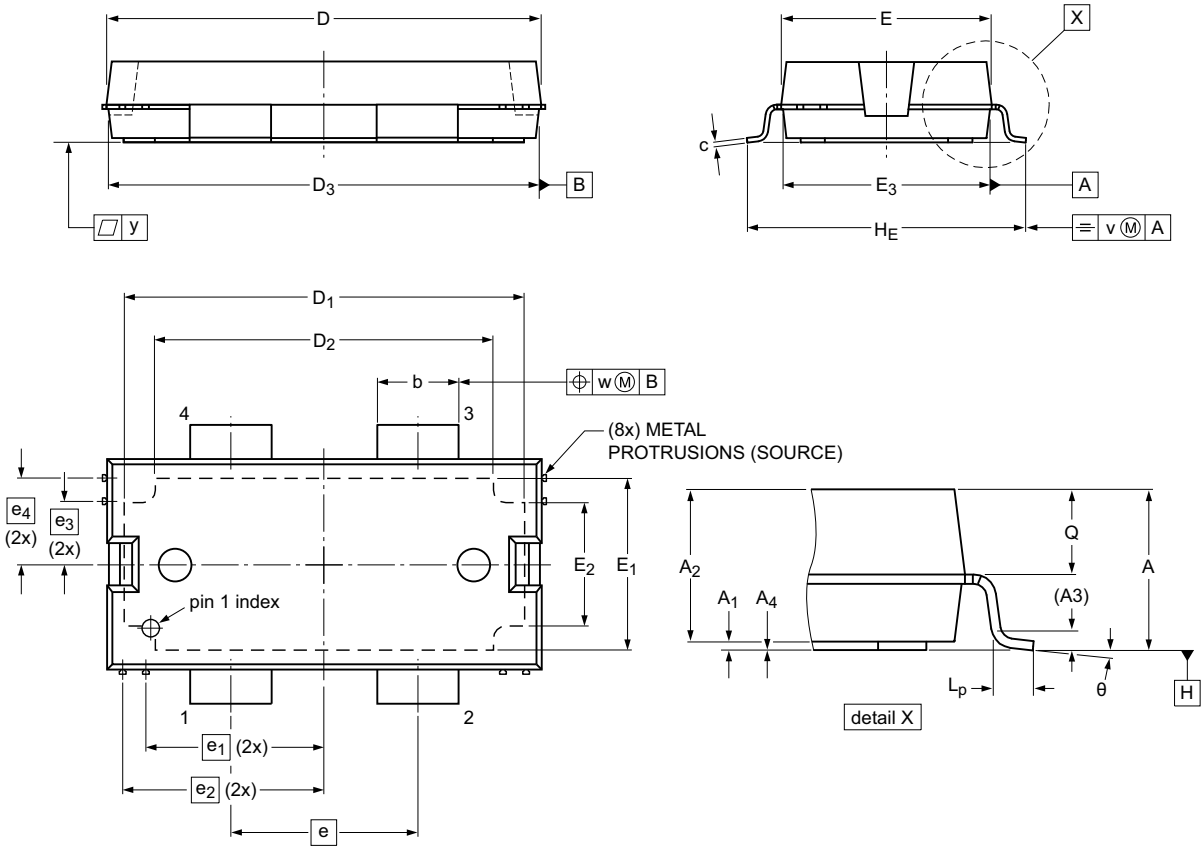
Note
1. Package body dimensions “D and “E do not include mold and metal protrusions. Allowable protrusion is 0.25 mm per side.
2. Lead width dimension “b does not include dambar protrusions. Allowable dambar protrusion is 0.25 mm in total per lead.

sot1223-2_po

Outline version	References				European projection	Issue date
	IEC	JEDEC	JEITA			
SOT1223-2						~~15-01-12~~ 15-06-04

Fig 12. Package outline SOT1223-2 (HSOP4F)

HSOP4: plastic, heatsink small outline package; 4 leads **SOT1224-2**



H_E	L_p	Q	v	w	y	θ
13.5	1.10	2.07			0.1	7°
13.2	0.95	2.02	0.25	0.25		3°
12.9	0.80	1.97				0°

Dimensions (mm are the original dimensions)

Unit		A	A_1	A_2	A_3	A_4	b	c	$D^{(1)}$	D_1	D_2	D_3	$E^{(1)}$	E_1	E_2	E_3	e	e_1	e_2	e_3	e_4
mm	max	3.9	0.2	3.65		0.06	3.90	0.27	20.62	19.00	16.05	20.44	10.01	8.18	5.89	9.83					
	nom		0.1	3.60	0.35	0	3.85	0.22	20.57	18.95	16.00	20.39	9.96	8.13	5.84	9.78	8.85	8.45	9.55	2.97	4.07
	min		0	3.55		-0.02	3.80	0.17	20.52	18.90	15.95	20.34	9.91	8.08	5.79	9.73					

Note
1. Package body dimensions “D and “E do not include mold and metal protrusions. Allowable protrusion is 0.25 mm per side.
2. Lead width dimension “b does not include dambar protrusions. Allowable dambar protrusion is 0.25 mm in total per lead.
3. Dimension A_4 is measured with respect to bottom of the heatsink DATUM H. Positive value means that the bottom of the heatsink is higher than the bottom of the lead.

sot1224-2_po

Outline version	References				European projection	Issue date
	IEC	JEDEC	JEITA			
SOT1224-2						~~15-01-13~~ 15-06-04

Fig 13. Package outline SOT1224-2 (HSOP4F)

9. Handling information

CAUTION

This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.

Such precautions are described in the *ANSI/ESD S20.20*, *IEC/ST 61340-5*, *JESD625-A* or equivalent standards.

10. Abbreviations

Table 12. Abbreviations

Acronym	Description
CW	Continuous Wave
DVB-T	Digital Video Broadcast - Terrestrial
ESD	ElectroStatic Discharge
HF	High Frequency
LDMOS	Laterally Diffused Metal-Oxide Semiconductor
MTF	Median Time to Failure
SMD	Surface Mounted Device
UIS	Unclamped Inductive Switching
VSWR	Voltage Standing-Wave Ratio

11. Revision history

Table 13. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BLP05H6150XR_H6150XRG v.4	20160921	Product data sheet	-	BLP05H6150XR v.3
Modifications	• The document now describes both the straight lead and gull-wing versions of this product: BLP05H6150XR and BLP05H6150XRG respectively • Table 2 on page 2: added BLP05H6150XRG data • Table 3 on page 2: added BLP05H6150XRG data • Section 7.1 on page 5: added BLP05H6150XRG • Figure 13 on page 12: added figure SOT1224-2			
BLP05H6150XR v.3	20160108	Product data sheet	-	BLP05H6150XR#2
BLP05H6150XR#2	20150901	Objective data sheet	-	BLP05H6150XR v.1
BLP05H6150XR v.1	20150518	Objective data sheet	-	-

12. Legal information

12.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.ampleon.com.

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ICs with DVB-T or DVB-T2 functionality

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13. Contact information

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